

FORM PTO 1449 (modified) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary)				ATTY DOCKET NO. <b>03560.003316.</b>		APPLICATION NO. <b>10/606,956</b>	
APPLICANT <b>HIDETOSHI TSUZUKI ET AL.</b>				FILING DATE <b>June 27, 2003</b>		GROUP <b>Unassigned</b>	
U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
LV	5,804,466	09/08/98	Arao et al.	438	95		
	6,068,755	05/30/00	Matsuda et al.	205	333		
	6,077,411	06/20/00	Nakamura	205	138		
	6,133,061	10/17/00	Sonoda	438	69		
	6,346,184 B1	02/12/02	Sano et al.	205	199		
	2002/0063065 A1	05/30/02	Sonoda et al.	205	333		
LV	6,576,112 B2	06/10/03	Sonoda et al.	205	155	09/17/01	
FOREIGN PATENT DOCUMENTS							
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT	
LV	JP 10-60686	03/03/98	Japan			Abstract	
	JP 10-140373	05/26/98	Japan			Abstract & USP 5804466	
	JP 10-195693	07/28/98	Japan			Abstract & USP 5804466	
	JP 10-259496	09/29/98	Japan			Abstract & USP 6077411	
	JP 11-286799	10/19/99	Japan			Abstract & USP 6133061	
	JP 2002-155396	05/31/02	Japan			Abstract	
LV	JP 2002-167695	06/11/02	Japan			Abstract & USP 6576112	
OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)							
LV	Sannomiya, et al.; "a-SiC/a-Si/a-SiGe Multi-Bandgap Stacked Solar Cells With Bandgap Profiling"; Int'l PVSEC-5, 387-390 (1990).						
	Inoue, et al.; "A light confinement effect in an a-SiGe solar cell on a 29 p-MF-22 stainless steel substrate"; Extended Abstracts Japan Soc. Applied Physics, 29-MF-2, p. 747 (1990).						
EXAMINER <i>Shan Van</i>				DATE CONSIDERED <i>6/8/25</i>			

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 608; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.